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FDS4435BZ P-Channel PowerTrench[®] MOSFET

FAIRCHILD

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FDS4435BZ P-Channel PowerTrench[®] MOSFET -30V, -8.8A, 20mΩ

Features

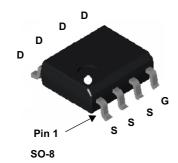
- Max $r_{DS(on)}$ = 20m Ω at V_{GS} = -10V, I_D = -8.8A
- Max $r_{DS(on)}$ = 35m Ω at V_{GS} = -4.5V, I_D = -6.7A
- Extended V_{GSS} range (-25V) for battery applications
- HBM ESD protection level of ±3.8KV typical (note 3)
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- Termination is Lead-free and RoHS compliant

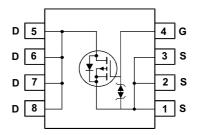


April 2009

General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units V		
V _{DS}	Drain to Source Voltage				-30	
V _{GS}	Gate to Source Voltage			±25	V	
ID	Drain Current -Continuous	T _A = 25°C	(Note 1a)	-8.8	Α	
	-Pulsed			-50		
P _D	Power Dissipation	T _A = 25°C	(Note 1a)	2.5	14/	
	Power Dissipation	T _A = 25°C	(Note 1b)	1.0	W	
E _{AS}	Single Pulse Avalanche Energy		(Note 4)	24	mJ	
T _J , T _{STG}	Operating and Storage Junction Temperation	ature Range		-55 to +150	°C	

Thermal Characteristics

$R_{\theta JC}$	ermal Resistance, Junction to Case 25		°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 50	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity	
FDS4435BZ	FDS4435BZ	SO-8	13"			

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
3V _{DSS}	Drain to Source Breakdown Voltage	I _D = -250μA, V _{GS} = 0V	-30			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250\mu$ A, referenced to 25°C		-21		mV/°C
DSS	Zero Gate Voltage Drain Current	V _{DS} = -24V, V _{GS} = 0V			1	μA
GSS	Gate to Source Leakage Current	V_{GS} = ±25V, V_{DS} = 0V			±10	μA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = -250μA	-1	-2.1	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{II}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \mu A$, referenced to 25°C		6		mV/°C
0		V _{GS} = -10V, I _D = -8.8A		16	20	
DS(on)	Static Drain to Source On Resistance	$V_{GS} = -4.5V, I_D = -6.7A$		26	35	mΩ
20(01)		V _{GS} = -10V, I _D = -8.8A, T _J = 125°C		22	28	
Ĵfs	Forward Transconductance	V _{DS} = -5V, I _D = -8.8A		24		S
Oynamic	Characteristics					
C _{iss}	Input Capacitance			1385	1845	pF
C _{oss}	Output Capacitance	─V _{DS} = -15V, V _{GS} = 0V, f = 1MHz		275	365	pF
C _{rss}	Reverse Transfer Capacitance			230	345	pF
۲ _g	Gate Resistance	f = 1MHz		4.5		Ω
Switching	Characteristics					
d(on)	Turn-On Delay Time			10	20	ns
r	Rise Time	$V_{DD} = -15V, I_D = -8.8A,$		6	12	ns
d(off)	Turn-Off Delay Time	$-V_{GS} = -10V, R_{GEN} = 6\Omega$		30	48	ns
f	Fall Time			12	22	ns
Q _q	Total Gate Charge	$V_{GS} = 0V \text{ to } -10V$ $V_{GS} = 0V \text{ to } -5V$ $V_{DD} = -15V,$ $I_D = -8.8A$		28	40	nC
2 ^ª	Total Gate Charge	$V_{GS} = 0V \text{ to } -5V$ $V_{DD} = -15V,$		16	23	nC
ລັ ລັ	Gate to Source Charge	I _D = -8.8A		5.2		nC
ວ _{gd}	Gate to Drain "Miller" Charge			7.4		nC
ງ Drain-Sou	urce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = -8.8A (Note 2)		-0.9	-1.2	V
rr	Reverse Recovery Time	I _F = -8.8A, di/dt = 100A/μs		29	44	ns
11	Reverse Recovery Charge	$F_{\rm F} = -0.0$ A, ui/ul = 100 A/µs		23	35	nC

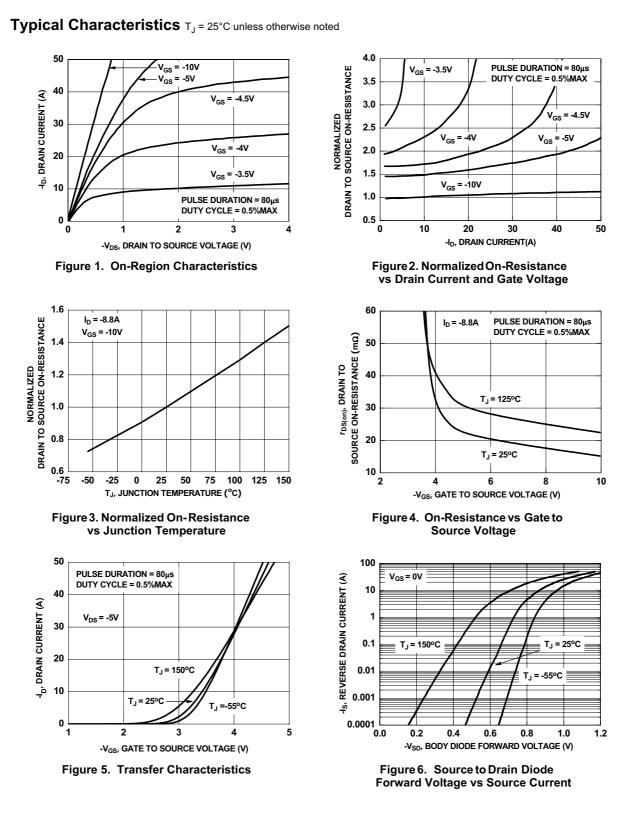
2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.

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3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

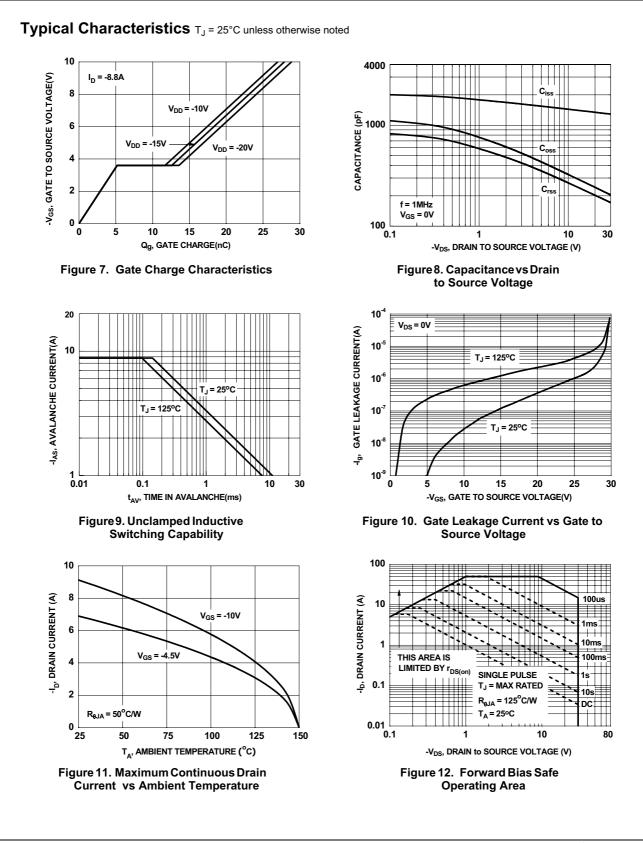
4. Starting T_J = 25°C, L = 1mH, I_{AS} = -7A, V_{DD} = -30V, V_{GS} = -10V





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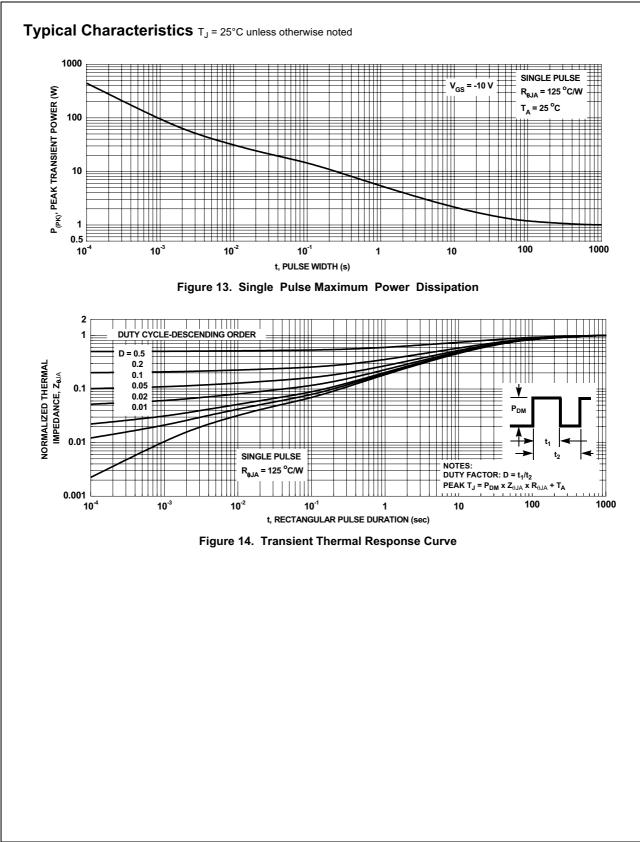
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FDS4435BZ P-Channel PowerTrench[®] MOSFET

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Product Status	Definition		
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First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		
-	First Production		

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